NSN 5961-00-605-6740

Unitized Semiconductor Devices - Page 1 of 1



/iew Online at https://aerobasegroup.com/nsn/5961-00-605-6740
nclosure Material:
Metal
Overall Length:
0.210 inches
Ferminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Electrode Internally-electrically Connected To Case:
Collector
Component Name And Quantity:
2 transistor
Mounting Method:
Геrminal
Ferminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
50.0 drain to source voltage all transistor
Current Rating Per Characteristic:
50.00 milliamperes gate current all transistor
Power Rating Per Characteristic:
500.0 milliwatts total power dissipation all transistor
Ferminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Jnit Of Measure:
-
Demilitarization:
No
Filg:
A110a0